

FAST CMOS 1-TO-10 CLOCK DRIVER

IDT74FCT807BT/CT

FEATURES:

- 0.5 MICRON CMOS Technology
- · Guaranteed low skew < 250ps (max.)
- Very low duty cycle distortion < 350ps (max.)
- · High speed: propagation delay < 2.5ns (max.)
- · 100MHz operation
- · TTL compatible inputs and outputs
- · TTL level output voltage swings
- 1:10 fanout
- Output rise and fall time < 1.5ns (max)
- Low input capacitance: 4.5pF typical
- High drive: -32mA Іон, +48mA Іоь
- · Available in QSOP, SSOP, and SOIC packages

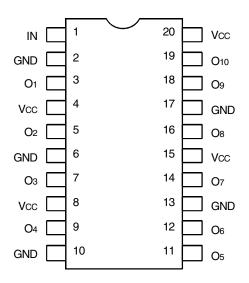
DESCRIPTION:

The FCT807T clock driver is built using advanced dual metal CMOS technology. This low skew clock driver features 1:10 fanout, providing minimal loading on the preceding drivers. The FCT807T offers low capacitance inputs with hysteresis for improved noise margins. TTL level outputs and multiple power and grounds reduce noise. The device also features -32/48mA drive capability for driving low impedance traces.

FUNCTIONAL BLOCK DIAGRAM

O1 O2 O2 O3 O4 O6 O7 O8 O9 O9

PIN CONFIGURATION



QSOP/ SOIC/ SSOP TOP VIEW

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ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-60 to +120	mA

NOTE:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
permanent damage to the device. This is a stress rating only and functional operation
of the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect reliability.

CAPACITANCE (TA = $+25^{\circ}$ C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	5.5	8	pF

NOTE:

PIN DESCRIPTION

Pin Names	Description		
IN	Inputs		
Ох	Outputs		

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Commercial: TA = 0° C to $+70^{\circ}$ C, Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = 5V \pm 5%

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level (Input pins)	Guaranteed Logic HIGH	Guaranteed Logic HIGH Level		_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW	Level	_	_	0.8	V
Іін	Input HIGH Current (Input pins)	Vcc = Max.	VI = 2.7V	_	_	±1	μΑ
lıL	Input LOW Current (Input pins)	Vcc = Max.	VI = 0.5V		_	±1	μΑ
lozн	High Impedance Output Current	Vcc = Max.	Vo = 2.7V	_	_	±1	μA
lozL	(3-State Output pins)		Vo = 0.5V	_	_	±1]
lı	Input HIGH Current	Vcc = Max., VI = Vcc	Vcc = Max., Vi = Vcc (Max.)		_	±1	μA
VIK	Clamp Diode Voltage	Vcc = Min., IIN = -18m.	VCC = Min., IIN = -18mA		-0.7	-1.2	V
los	Short Circuit Current ⁽⁴⁾	Vcc = Max., Vo = GNI) ⁽³⁾	-60	-120	-225	mA
Vон	Output HIGH Voltage	Vcc = Min.	Iон = -15mA	2.4	3.3	_	V
		VIN = VIH or VIL	IOH = -32mA	2	3	_]
Vol	Output LOW Voltage	Vcc = Min.	IoL = 48mA	<u> </u>	0.3	0.55	V
		VIN = VIH or VIL					
loff	Input/Output Power Off Leakage	Vcc = 0V, Vin or Vo ≤	4.5V	_	_	±1	μA
VH	Input Hysteresis for all inputs	_		_	150	_	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = Max., Vin = GNI	O or Vcc	_	5	500	μΑ

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5V, +25°C ambient.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. Duration of the condition should not exceed one second.

^{1.} This parameter is measured at characterization but not tested.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Con	ditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
∆lcc	Quiescent Power Supply Current	Vcc = Max.		_	0.5	2	mA
	TTL Inputs HIGH	VIN = 3.4V					
ICCD	Dynamic Power Supply Current ⁽³⁾	Vcc = Max.	VIN = VCC	_	0.4	0.6	mA/MHz
		Input Toggling	VIN = GND				
		50% Duty Cycle					
		Outputs Open					
Ic	Total Power Supply Current ⁽⁵⁾	Vcc = Max.	VIN = VCC	_	20	30.5 ⁽⁴⁾	mA
		Input Toggling	VIN = GND				
		50% Duty Cycle					
		Outputs Open	VIN = 3.4V	_	20.3	31.3 ⁽⁴⁾	
		fı = 50MHz	VIN = GND				

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5V, +25°C ambient.
- 3. Per TTL driven input (VIN = 3.4V); all other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
- 5. Values for these conditions are examples of the lc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
 - $IC = ICC + \Delta ICC DHNT + ICCD (foNo)$
 - Icc = Quiescent Current (Iccl, IccH and Iccz)
 - Δ Icc = Power Supply Current for a TTL High Input (VIN = 3.4V)
 - DH = Duty Cycle for TTL Inputs High
 - NT = Number of TTL Inputs at DH
 - ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
 - fo = Output Frequency
 - No = Number of Outputs at fo
 - All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - COMMERCIAL (3,4)

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tPLH tPHL	Propagation Delay	50Ω to Vcc/2, CL = 10pF	1.3	2.7	1.3	2.5	ns
₽	Output Rise Time	(See figure 1) or 50Ω ac	_	1.5	_	1.5	ns
tF	Output Fall Time	termination,	_	1.5	_	1.5	ns
tsk(0)	Output skew: skew between outputs of all banks of same package (inputs tied together)	CL = 10pF (See figure 2)	_	0.5	_	0.25	ns
tsk(P)	Pulse skew: skew between opposite transitions of same output (tphltplh)	f ≤100MHz Outputs connected in groups of two	_	0.5		0.35	ns
tsk(T)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade	groups of two	_	0.9	_	0.65	ns

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tPLH tPHL	Propagation Delay	CL = 30pF f ≤67MHz	1.5	3.8	1.5	3.5	ns
tr	Output Rise Time	(See figure 3)	_	1.5	_	1.5	ns
tF	Output Fall Time		_	1.5	_	1.5	ns
tsk(0)	Output skew: skew between outputs of all banks of same package (inputs tied together)		_	0.5	_	0.25	ns
tsk(P)	Pulse skew: skew between opposite transitions of same output (tphltplh)		_	0.5	_	0.35	ns
tsk(T)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		_	0.9	_	0.75	ns

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tPLH	Propagation Delay	CL = 30pF	1.5	3.8	1.5	3.5	ns
tphl		f ≤40MHz					
₽	Output Rise Time	(See figure 4)	_	1.5	_	1.5	ns
tF	Output Fall Time		_	1.5	_	1.5	ns
tsk(o)	Output skew: skew between outputs of all banks of		_	0.5	_	0.35	ns
	same package (inputs tied together)						
tsk(P)	Pulse skew: skew between opposite transitions		_	0.6	_	0.45	ns
	of same output (tphltplh)						
tsk(T)	Package skew: skew between outputs of different		_	1	_	0.75	ns
	packages at same power supply voltage,						
	temperature, package type and speed grade						

- 1. See test circuits and waveforms.
- 2. Minimum limits are guaranteed but not tested on Propagation Delays.
- 3. tPLH, tPHL, tsk(t) are production tested. All other parameters guaranteed but not production tested.
- 4. Propagation delay range indicated by Min. and Max. limit is due to Vcc, operating temperature and process parameters. These propagation delay limits do not imply skew.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - INDUSTRIAL (3,4)

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tPLH tPHL	Propagation Delay	50Ωto Vcc/2, CL = 10pF	1.3	2.9	1.3	2.7	ns
₽	Output Rise Time	(See figure 1) or 50Ω ac	_	1.5	_	1.5	ns
tF	Output Fall Time	termination,	_	1.5	_	1.5	ns
tsk(0)	Output skew: skew between outputs of all banks of same package (inputs tied together)	CL = 10pF (See figure 2)	_	0.6	_	0.35	ns
tsk(P)	Pulse skew: skew between opposite transitions of same output (tphl tplh)	f ≤100MHz Outputs connected in groups of two	_	0.6	-	0.45	ns
tsk(T)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade	groups of two	_	0.9	_	0.65	ns

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tPLH tPHL	Propagation Delay	CL = 30pF f ≤67MHz	1.5	4	1.5	3.7	ns
t R	Output Rise Time	(See figure 3)	_	1.5	_	1.5	ns
tF	Output Fall Time		_	1.5	_	1.5	ns
tsk(0)	Output skew: skew between outputs of all banks of same package (inputs tied together)		_	0.6	_	0.35	ns
tsk(P)	Pulse skew: skew between opposite transitions of same output (tphltplh)		_	0.6	_	0.45	ns
tsk(T)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		_	0.9	_	0.75	ns

			FCT8	07BT	FCT8	07CT	
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
tplh tphl	Propagation Delay	CL = 30pF f ≤40MHz	1.5	4	1.5	3.7	ns
tR	Output Rise Time	(See figure 4)	_	1.5	_	1.5	ns
tF	Output Fall Time		_	1.5	_	1.5	ns
tsk(0)	Output skew: skew between outputs of all banks of same package (inputs tied together)		_	0.6	_	0.45	ns
tsk(P)	Pulse skew: skew between opposite transitions of same output (tphltplh)		_	0.7	_	0.55	ns
tsk(t)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		_	1	_	0.75	ns

- 1. See test circuits and waveforms.
- 3. tplh, tphl, tsk(t) are production tested. All other parameters guaranteed but not production tested.
- 4. Propagation delay range indicated by Min. and Max. limit is due to Vcc, operating temperature and process parameters. These propagation delay limits do not imply skew.

TEST CIRCUITS

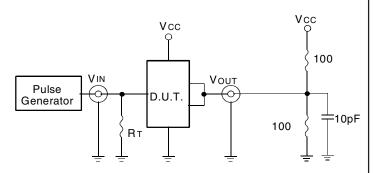


Fig. 1: 50Ω to Vcc/2, CL = 10pF

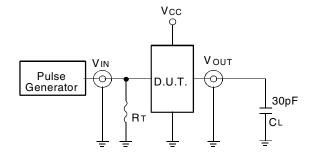


Fig. 3: CL = 30pF Circuit

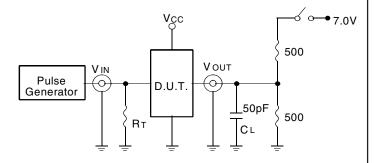


Fig. 5: Enable and Disable Time Circuit

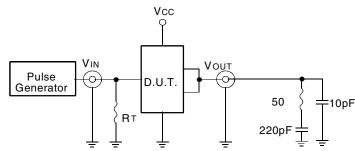


Fig. 2: 50Ω AC Termination, CL = 10pF

The capacitor value for AC termination is determined by the operating frequency. For very low frequencies a higher capacitor value should be selected.

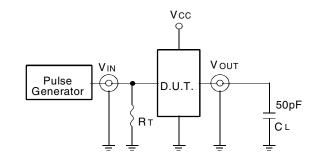


Fig. 4: CL = 50pF Circuit

SWITCH POSITION

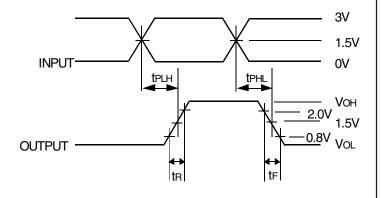
Test	Switch
Disable LOW Enable LOW	6V
Disable HIGH Enable HIGH	GND

DEFINITIONS:

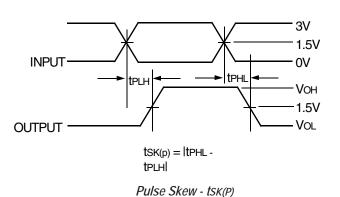
CL = Load capacitance: includes jig and probe capacitance.

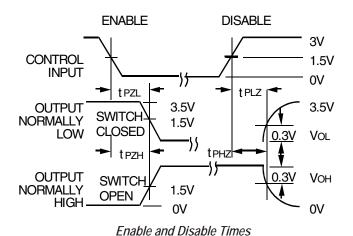
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

TEST WAVEFORMS



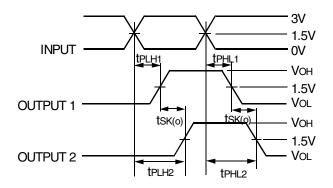
Package Delay





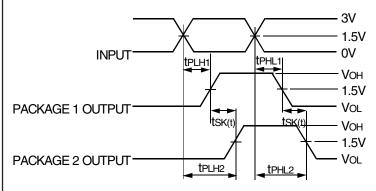
NOTES:

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH
- 2. Pulse Generator for All Pulses: Rate ≤1.0MHz; tF ≤2.5ns; tR ≤2.5ns



tSK(o) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

Output Skew - tsk(0)



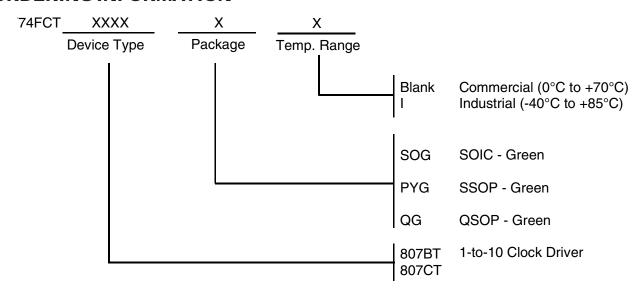
tSK(t) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

Part-to-Part Skew - tsk(T)

NOTE:

1. Package 1 and Package 2 are same device type and speed grade.

ORDERING INFORMATION



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